

Single-Chip Electronic Volume Control System



Overview

The LC75394NE is an electronic volume control system providing control over volume, balance, 5-band equalizer, and input switching based on serial inputs.

Functions

• Volume control:

The chip provides 25 levels of volume attenuation: in 2-dB steps between 0 dB and -20 dB, 3-dB steps between -20 dB and -32 dB, 4-dB steps between -32 dB and -52 dB, 4.5-dB steps between -52 dB and -70 dB, and $-\infty$. Independent control over left and right channels provides balance control.

• Equalizer:

The chip provides control in 2-dB steps over the range between +10 dB and -10 dB. Four of the five bands have peaking equalization; the remaining one, shelving equalization.

• Selector:

The left and right channels each offer a choice of four inputs. An external constant determines the amplification for the input signal.

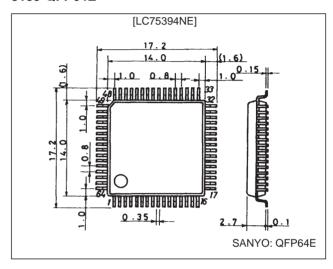
Features

- Built-in buffer amplifiers reduce the number of external parts necessary.
- Silicon gate CMOS reduces switching noise.
- · Serial data input
 - —Supports CCB* format communication with the system controller.
- A built-in reference voltage circuit divides the supply voltage (V_{DD}) in half.

Package Dimensions

unit: mm

3159-QFP64E



*

- CCB is a trademark of SANYO ELECTRIC CO., LTD.
- CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$, $V_{SS} = 0~V$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max	V _{DD}	12	V
Maximum input voltage	V _{IN} max	CL, DI, CE, L1 to L4, R1 to R4, LTIN, RTIN, LVRIN, RVRIN	$V_{SS} - 0.3 \text{ to} $ $V_{DD} + 0.3$	V
Allowable power dissipation	Pd max	Ta ≤ 85°C	310	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +125	°C

Allowable Operating Ranges at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply voltage	V _{DD}	V _{DD}	6.0		11.0	V
Input high level voltage	V _{IH}	CL, DI, CE	4.0		V _{DD}	V
Input low level voltage	V _{IL}	CL, DI, CE	V _{SS}		1.0	V
Input voltage amplitude	V _{IN}	CL, DI, CE, L1 to L4, R1 to R4, LTIN, RTIN, LVRIN, RVRIN	V _{SS}		V _{DD}	Vp-p
Input pulse width	t _{øW}	CL	1.0			μs
Setup time	t _{SETUP}	CL, DI, CE	1.0			μs
Hold time	t _{HOLD}	CL, DI, CE	1.0			μs
Operating frequency	fopg	CL			500	kHz

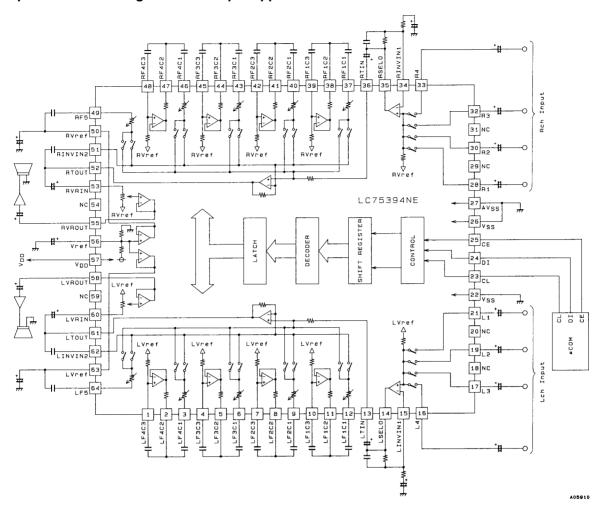
Electrical Characteristics at $Ta=25^{\circ}C,\,V_{DD}=10~V,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	min	typ	max	Unit
[Input block]						
Input resistance	Rin	L1 to L4, R1 to R4		1		ΜΩ
Clipping level	Vcl	LSELO, RSELO: THD = 1.0%		2.65		Vrms
Output load resistance	R _L	LSELO, RSELO	3			kΩ
[Volume control block]						•
Input resistance	Rin	LVRIN, RVRIN	60	100	140	kΩ
[Equalizer control block]			•			•
Control range	Geq	Max, boost/cut	±8	±10	±12	dB
Step resolution	Estep		1	2	3	dB
Internal feedback resistance	Rfeed		17	28	39	kΩ
[Overall characteristics]			•			•
Total harmonic distortion	THD (1)	V _{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall		0.0033		%
Total narmonic distortion	THD (2)	V _{IN} = 1 Vrms, f = 20 kHz, with all controls flat overall		0.012		%
Crosstalk	СТ	V_{IN} = 1 Vrms, f = 1 kHz, with all controls flat overall, Rg = 1 k Ω		86		dB
Output at maximum attenuation	V _O min	V _{IN} = 1 Vrms, f = 1 kHz, main volume -∞		-90		dB
Outrat a sissantia	V _N (1)	With all controls flat overall (IHF-A), Rg = 1 k Ω		3.9		μV
Output noise voltage	V _N (2)	With all controls flat overall (DIN-AUDIO), Rg = 1 k Ω		5.4		μV
Current drain	I _{DD}	V _{DD} - V _{SS} = 11 V		25	33	mA
Input high level current	I _{IH}	CL, DI, CE, V _{IN} = 11 V			10	μA
Input low level current	I _{IL}	CL, DI, CE, V _{IN} = 0 V	-10			μA

Input Amplifier Characteristics at $Ta=25^{\circ}C,\,V_{DD}-V_{SS}=10~V$

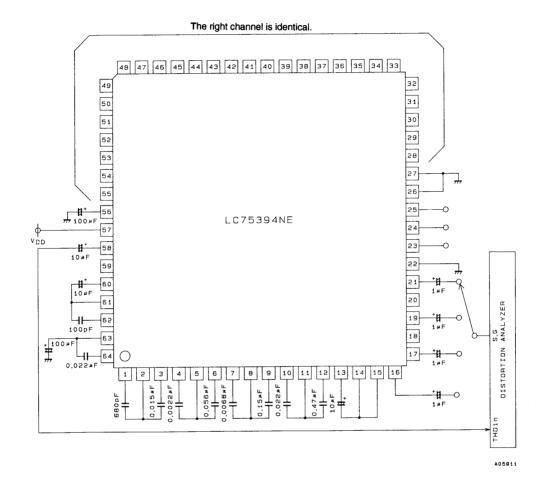
Parameter	Symbol	Conditions	min	typ	max	Unit
Input offset voltage	V _{IO}		-10		+10	mV
Input offset current	I _{IO}	$V_{SS} \le V_{IN} \le V_{DD}$		±10		nA
Open-loop voltage gain	A _O			80		dB
Width of 0 dB band	f _T			2.5		MHz
Allowable load resistance	R _L		3			kΩ

Equivalent Block Diagram and Sample Application Circuit

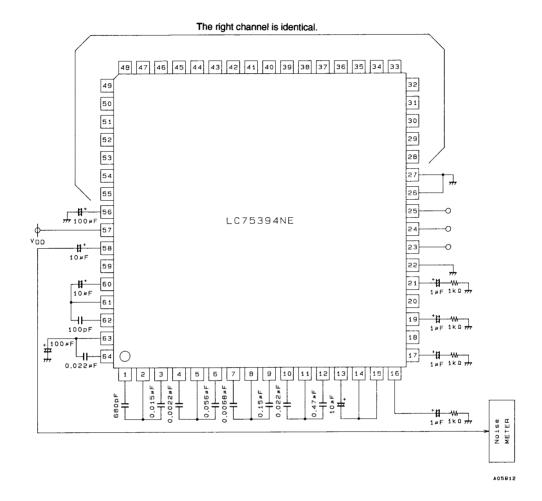


Test Circuits

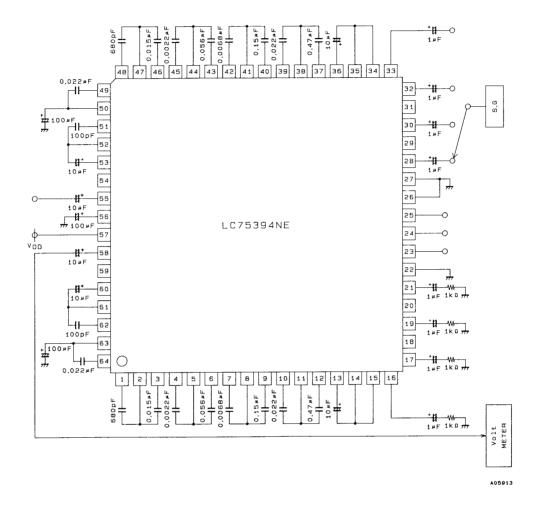
1. Total Harmonic Distortion



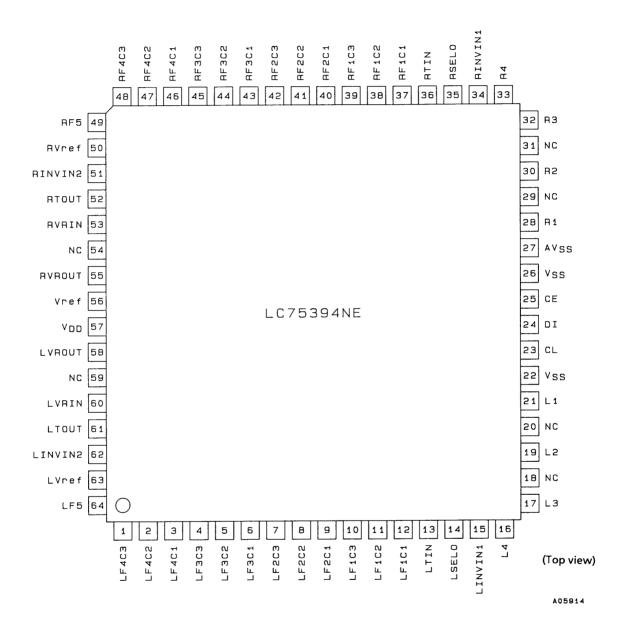
2. Output Noise Voltage



3. Crosstalk



Pin Assignment



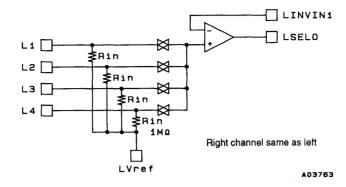
Pin Functions

12	Symbol LF1C1 LF1C2 LF1C3 RF1C1 RF1C2 RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C1 RF4C1 LF4C2 LF4C3 RF4C1 RF4C2 RF4C3	F1 band control block for left channel. Connect to external capacitors. F1 band control block for right channel. Connect to external capacitors. F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	Note VDD Vref VDD Vref VDD Vref A03750
11	LF1C2 LF1C3 RF1C1 RF1C2 RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C1 RF3C2 RF3C3 RF4C1 RF4C2 LF4C3	F1 band control block for right channel. Connect to external capacitors. F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors.	Vref Vref Vref Vref Vref
10 II 37 F 38 F 39 F 9 II 40 F 41 F 42 F 6 II 43 F 44 F 45 F 3 II 46 F 47 F 48 F	RF1C1 RF1C2 RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF4C1 RF4C2 LF4C3 RF4C1 RF4C2	F1 band control block for right channel. Connect to external capacitors. F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	Vref Vref Vref Vref Vref
38	RF1C2 RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	Vref Vref Vref Vref Vref
38	RF1C2 RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	Vref Vref Vref Vref Vref
39 F 9	RF1C3 LF2C1 LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for left channel. Connect to external capacitors. F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors.	VDD Vref
8	LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	OVDD Vref
8	LF2C2 LF2C3 RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	Vref Vref Vref Vref Vref Vref Vref Vref
7	RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F2 band control block for right channel. Connect to external capacitors. F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	OVDD FnC2 OVDD AVSS FnC3 Vref
40 F 41 F 42 F 6 F 44 F 48 F 6 F 13	RF2C1 RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	OVDD FnC2 OVDD AVSS FnC3 Vref
41 F F F F F F F F F F F F F F F F F F F	RF2C2 RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external capacitors.	PINC2 AVSS PINC3 VDD Vref
42 F 6 I 5 I 4 I 43 F 44 F 45 F 3 I 2 I 1 I 46 F 48 F	RF2C3 LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for left channel. Connect to external capacitors. F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors.	PINC2 VDD AVSS Vref
6 I 5 I 4 I 1 43 F 44 F 45 F 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	LF3C1 LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	AVSS PNC3
5	LF3C2 LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	AVSS Procedure of the second o
4 I 43 F 44 F 45 F 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	LF3C3 RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F3 band control block for right channel. Connect to external capacitors. F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	AVSS FnC3
43 F 44 F 45 F 13 L 146 F 48 F 13	RF3C1 RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	PNC3
44 F F F F F F F F F F F F F F F F F F	RF3C2 RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	Vref
45 F 3 I 2 I 1 I 46 F 47 F 48 F	RF3C3 LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	F4 band control block for left channel. Connect to external capacitors. F4 band control block for right channel. Connect to external	VDD ▼ Vref
3 I I I I I I I I I I I I I I I I I I I	LF4C1 LF4C2 LF4C3 RF4C1 RF4C2	capacitors. F4 band control block for right channel. Connect to external	Vref
2 I 1 I 46 F 47 F 48 F	LF4C2 LF4C3 RF4C1 RF4C2	capacitors. F4 band control block for right channel. Connect to external	<u> </u>
1 I I I I I I I I I I I I I I I I I I I	RF4C1 RF4C2	capacitors. F4 band control block for right channel. Connect to external	A03750
46 F 47 F 48 F	RF4C1 RF4C2		
47 F 48 F	RF4C2		
48 F			I .
13	RF4C3	capacitore.	
			, ov DD
36	LTIN	Tone control inputs. Must be driven with low-impedance	
	RTIN	circuits.	
			A03751
			9INVIN1 9VDD
14 L	LSELO		<u> </u>
35 F	RSELO	Input selector outputs	
			Vref 0 AVSS 0 777
			و۷۵۵
64	LF5	FEL. 1	
49	RF5	F5 band control block. Connect to external capacitors.	→
			A03753
21	L1		
19	L2		, voo
17	L3		→
16 28	L4 R1	Signal inputs	
30	R2		AVSSO
			AVSS INVIN1
33			
		Power supply connection	
5/		Power supply connection	
22, 26	V _{SS}	Grounds for internal logic	
27		Ground for internal operational amplifier	
57	R3 R4 V _{DD} V _{SS}	Power supply connection Grounds for internal logic	A03754

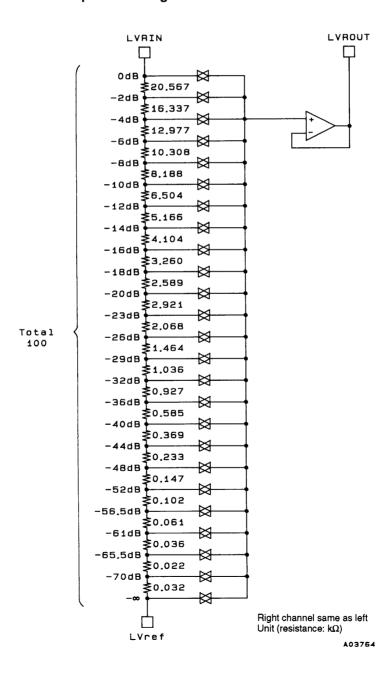
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Pin No.	Symbol	Function	Note
	,		٩٧٥٥
56	Vref	$\rm V_{DD}\!/2$ voltage generator block. Connect capacitors between Vref and $\rm V_{SS}$ to minimize the effects of power supply ripple.	Vrefo OAVSS 777 A03755
63 50	LVref RVref	Pins common to volume control, tone control, and input selection blocks. Select the capacitors between these pins and V_{SS} carefully as they contribute residual resistance when the volume is turned down. The voltage must never exceed V_{DD} .	VRIN VDD VROUT VROUT VROUT VROUT VROUT VROUT VROUT A03786
15 34	LINVIN1 RINVIN1	Operational amplifier inverted input for specifying input gain.	AVSS A03757
62 51	LINVIN2 RINVIN2	Operational amplifier inverted input for specifying graphic equalization. Connecting a capacitor across INVIN2 and TOUT permits the removal of unwanted bands and reduces the risk of oscillation.	AVSS A03756
61 52	LTOUT RTOUT	Tone control output	A03759
60 53	LVRIN RVRIN	Volume control input. Must be driven with low-impedance circuits.	→ VDD ★ A A03760
58 55	LVROUT RVROUT	Volume control output	A03761
25	CE	Chip enable pin. The chip uses falling edge timing to write data to the internal latch and shift analog switches. The high level enables data transfer.	Z
24	DI		A03762
23	CL	Serial data and clock input used for control	
18	NC		
20	NC NC		
29	NC		
31	NC	Leave unconnected	
54	NC		
59	NC		
	l		No. 5466-9/17

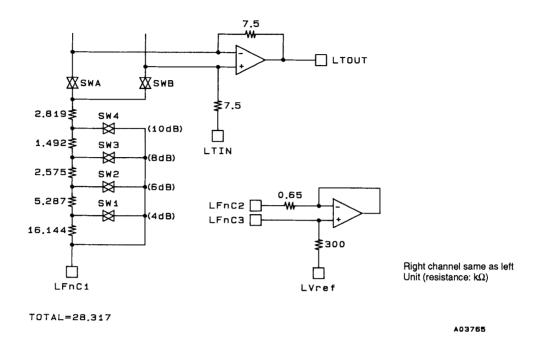
Input Block Internal Equivalent Circuit Diagram



Volume Control Block Internal Equivalent Diagram



Equalizer Control Block Internal Equivalent Circuit (Bands F1 to F4)

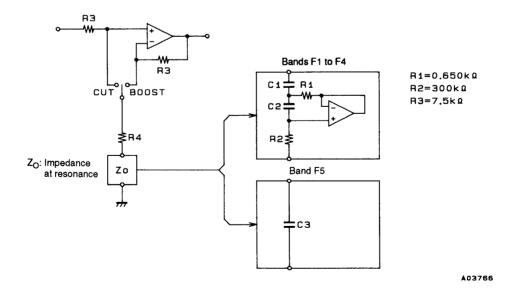


Calculating the Size of External Capacitors

The LC75394NE supports four bands with peaking characteristics and one band with shelving characteristics

- 1. Peaking Characteristics (bands F1 to F4)

 The external capacitor functions as the structural element of a simulated inductor. The equivalent circuit and the calculations required to achieve the desired center frequency are shown below.
 - Equivalent circuit for the simulated inductor



• Calculation example

Specifications: Central frequency, $F_O = 107 \text{ Hz}$

Q factor at maximum boost, $Q_{+10 \text{ dB}} = 0.8$

— Calculate Q_O, the sharpness of the simulated inductance itself.

$$Q_O = (R1 + R4)/R1 \times Q_{+10dB}$$

Note: R4 is from the separately issued internal block diagram.

$$\neq 4.270$$

— Calculate C1

$$C1 = 1/2\pi F_{O}R1Q_{O} \neq 0.536 (\mu F)$$

— Calculate C2

$$C2 = Q_0/2\pi F_0 R2 \neq 0.021 (\mu F)$$

• Sample results

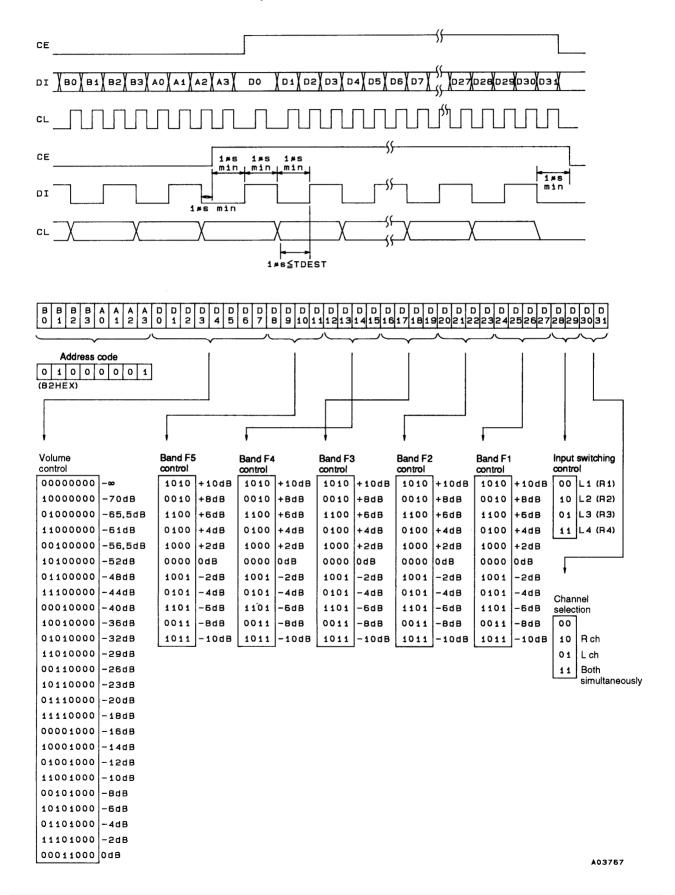
Central frequency F _O (Hz)	C1 (F)	C2 (F)
107	0.536 μ	0.021 μ
340	0.169 μ	6663 _P
1070	0.054 μ	2117 _P
3400	0.017 μ	666 _P

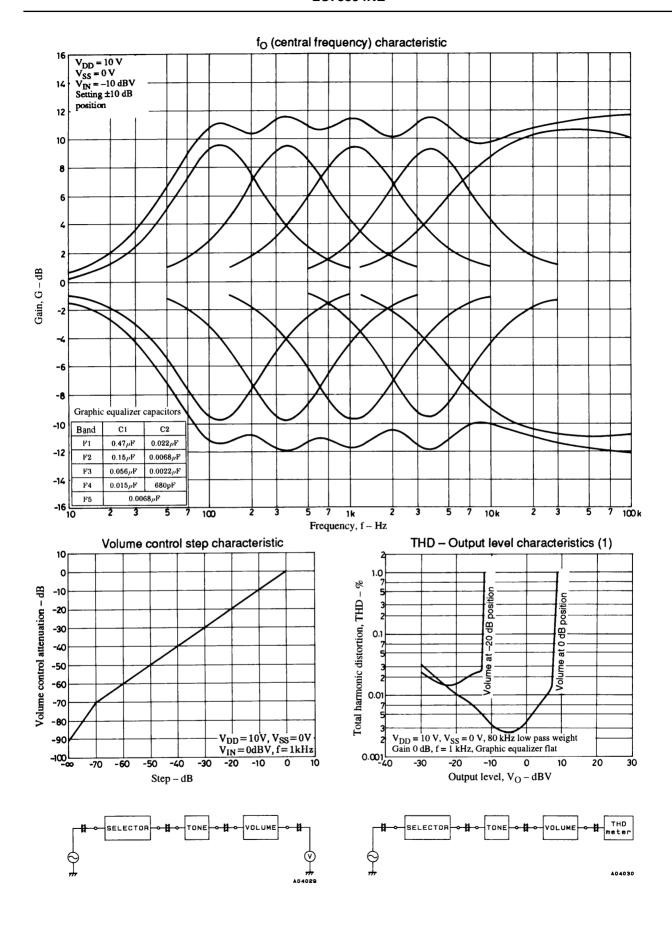
• Shelving characteristics (Band F5)

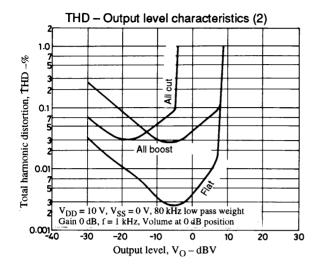
Achieving the desired control of 2-dB steps over the range between +10 dB to -10 dB requires choosing a capacitor, C3, with an impedance of 650 Ω .

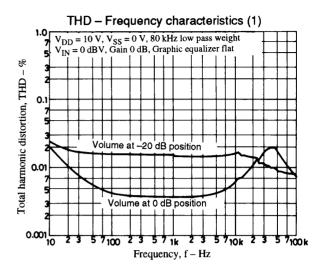
Control System Timing and Data Formats

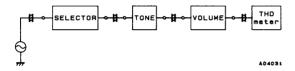
The LC75394NE receives its control sequences via a serial interface comprised of pins CE, CL, and DI. Each sequence consists of 40 bits: an 8-bit address followed by 32 bits of data.

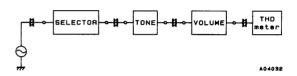


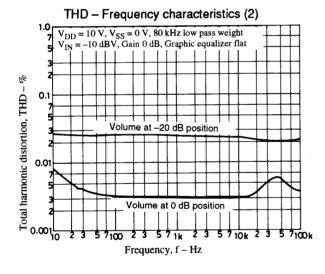


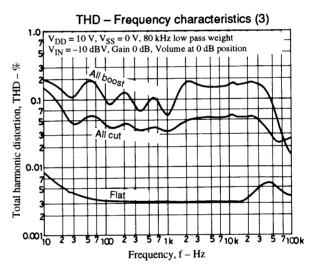


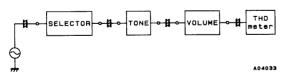


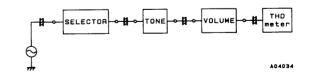


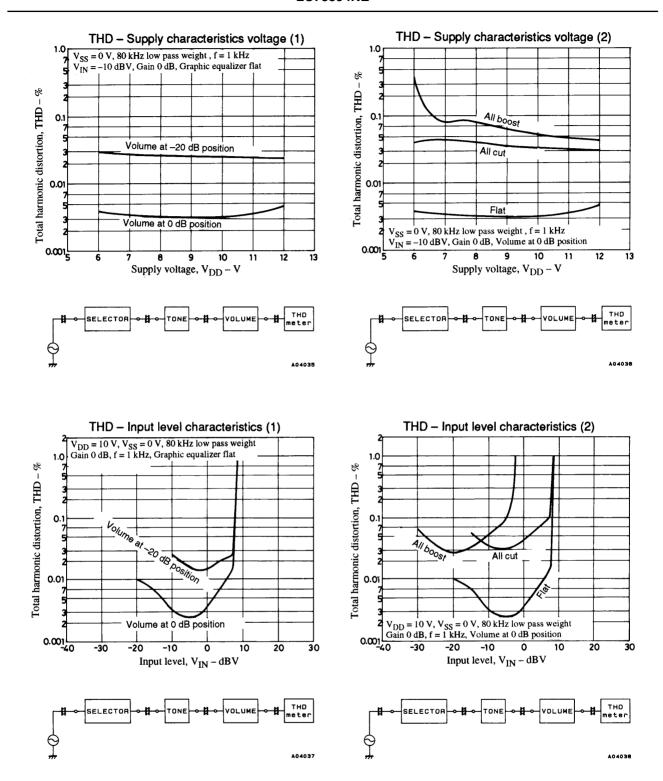












Usage Notes

- 1. When the power is first applied, the internal analog switches are in indeterminate states. The chip therefore requires muting or other external measures until it has received the proper data.
- 2. Provide grounding patterns or shielding for the lines to the CL, DI, and CE pins so as to prevent their high-frequency data signals from interfering with the operation of nearby analog circuits.

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